

# Minho Kim

## List of Publications by Year in descending order

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#	ARTICLE	IF	CITATIONS
1	Defect reduction of SiN <sub>x</sub> embedded m-plane GaN grown by hydride vapor phase epitaxy. Journal of Crystal Growth, 2014, 407, 6-10.	1.5	10
2	Novel in situ self-separation of a 2 in. free-standing m-plane GaN wafer from an m-plane sapphire substrate by HCl chemical reaction etching in hydride vapor-phase epitaxy. CrystEngComm, 2016, 18, 7690-7695.	2.6	4
3	On/off-state noise characteristics in AlGaIn/GaN HFET with AlN buffer layer. Applied Physics Letters, 2022, 120, .	3.3	4
4	Void containing AlN layer grown on AlN nanorods fabricated by polarity selective epitaxy and etching method. AIP Advances, 2021, 11, 045036.	1.3	2
5	Microstructural Gradational Properties of Sn-Doped Gallium Oxide Heteroepitaxial Layers Grown Using Mist Chemical Vapor Deposition. Materials, 2022, 15, 1050.	2.9	2
6	Growth of self-assembled nanovoids embedded AlN layer on a low- temperature buffer by metal organic chemical vapor deposition. Thin Solid Films, 2022, 752, 139261.	1.8	2